# Photodigm VVV

## Specification Sheet | 935 nm Series

Distributed Bragg Reflector (DBR) Laser Diode



Chip on Submount (CoS)



CoS + Mode-Hop Free (MHF)

### Description

The 935 nm DBR Series of high-performance edge-emitting laser diodes are based on Photodigm's advanced monolithic single-frequency Gallium Arsenide (GaAs) based laser technology. It provides a single spatial mode beam and has passivated facets for reliability. The 935 nm Series DBR devices are used in atomic spectroscopy for ytterbium-based (Yb) applications.

## 935 nm DBR Chip on Submount (CoS) Characteristics

	Chip Architecture
Parameters <sup>1</sup>	High Power
Wavelength, Nominal (nm) <sup>2</sup>	935 ± 1.0
Power Range (mW)	80–180
Operating Current, Max (CW & Pulsed) (mA)	350
Optical Power at Max Operating Current (mW)	240
Slope Efficiency, Nominal (W/A)	0.9
Threshold Current, Nominal (mA)	30

1. Characteristics at T<sub>c</sub> = 25 °C unless otherwise specified. Operating outside of these parameters voids warranty.

2. Hermetically sealed packages may contain CoS that are  $\pm$  1.2 nm from nominal

## Available Free-Space Package Add-ons





C-Mount



Transmitter Optical Subassembly (TOSA)



## Specification Sheet | 935 nm Series

Distributed Bragg Reflector (DBR) Laser Diode **Specifications** 

#### Laser

Parameter	Unit	Min	Typical	Max	
Storage Temperature	°C	0	-	70	
Operating Temperature at case	°C	5	-	70	
Operating Temperature at laser chip <sup>1</sup>	°C	5	-	45	
Laser Series Resistance	Ω	-	2	-	
Laser Forward Voltage @ LIV Current	V	-	2	-	
Nominal Laser Linewidth @ LIV Current	kHz	-	500	-	
Beam Divergence @ FWHM ( $\theta_{  } x \theta_{\perp}$ )	ō	-	6 x 28	8 x 32	
Side Mode Suppression Ratio (SMSR)	dB	-	-40	-	
Polarization Extinction Ratio	dB	-17	-20	-	
Laser Polarization	TE				
Mode Structure	Fundamental Mode				
Temperature Tuning Rate	nm/°C	-	0.06	-	
Current Tuning Rate	nm/mA	-	0.002	-	
Laser Reverse Voltage	V	-	-	0	

1. Operation below dew point not recommended without hermetically sealed packaged

#### Free-Space Package Add-Ons

Parameter	Unit	Min	Typical	Max
Photodiode Forward Current	mA	-	-	10
Photodiode Reverse Voltage	V	-	-	50
TEC Current (TOSA)	А	-1.1	-	1.1
TEC Voltage (TOSA)	V	-3.0	-	3.0
TEC Current (TO-8)	А	-1.8	-	1.8
TEC Voltage (TO-8)	V	-2.2	-	2.2
Thermistor Resistance	kΩ	-	10	-

## **Handling Precautions**

These devices are sensitive to ESD. When handling the module, grounded work area and wrist strap must be used. Always store in an antistatic container with all leads shorted together.





Photodigm, Inc. reserves the right to make changes in design, specifications, and other information at any time, and without prior notice. The information contained within the specification sheet is believed to be accurate. However, no responsibility is assumed for possible inaccuracy or omission. Any information contained herein shall not legally bind Photodigm, Inc. unless it is specifically incorporated in the terms and conditions of a sales agreement.



## Specification Sheet | 935 nm Series

Distributed Bragg Reflector (DBR) Laser Diode

